Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2	"20040217427"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:19
S2	907	@ad<="20040401" and (257/370).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:21
S3	693	@ad<="20040401" and (257/378).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 11:42
S4	272	@ad<="20040401" and (257/361).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 11:43
S5	122	@ad<="20040401" and (257/497).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 11:43
S8	1	@ad<="20040401" and 'first well' and 'second well' and 'third well' and 'bias voltage' and 'pad' and 'BJT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:00
S9	5	@ad<="20040401" and 'first well' and 'second well' and 'third well' and 'voltage' and 'pad' and 'BJT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 11:57
S10	13	@ad<="20040401" and 'first well' and 'second well' and 'third well' and 'voltage' and 'BJT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 11:57
S11	69	@ad<="20040401" and 'first well' and 'second well' and 'third well' and 'voltage' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 14:07
S12	1325	@ad<="20040401" and (257/371-373).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 12:10
S13	35	@ad<="20040401" and 'first well' and 'second well' and 'third well' and 'pad' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:31

S14	1	"5894145".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:14
S15	1	"5786617".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:16
S16	1	"5637900".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:17
S17	1	"5329143".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:19
S18	42	'Ker Ming-Dou' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 07:53
S19	1	"5400202".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:32
S20	1	'Ahn Soon-Hong' and 'BJT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 12:41
S21	2	'Ahn Soon-Hong'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 12:42
S22	26	'Lee Jung-Hwa'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 12:42
S23	75	@ad<="20040401" and 'ESD' and 'IGBT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 13:48
S24	1	"6507471".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:55
S25	1	"6469560".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:55
S26	1	"6437419".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:56
S27	1	"6414532".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:56
S28	1	"6320232".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:56
S29	1	"6002155".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:57
S30	1	"5955763".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:58
S31	1	"5932914".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:58
S32	1	"5880501".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:58

S33	1	"6225649".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:59
S34	1	"6194764".PN.	USPAT; USOCR	OR	ON	2005/06/14 12:59
S35	1	"6097235".PN.	USPAT; USOCR	OR	ON	2005/06/14 13:00
S36	1	"5330922".PN.	USPAT; USOCR	OR	ON	2005/06/14 13:20
S37	1	"5132235".PN.	USPAT; USOCR	OR	ON	2005/06/14 13:21
S38	1	"5102811".PN.	USPAT; USOCR	OR	ON	2005/06/14 13:23
S39	1	"6365940".PN.	USPAT; USOCR	OR	ON	2005/06/14 13:33
S40	1	"5959332".PN.	USPAT; USOCR	OR	ON	2005/06/14 13:33
S41	36	'Gossner Harald'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 13:48
S42	12	@ad<="20040401" and 'Nwell' and 'Pwell' and 'Pwell' and 'deep well'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 14:05
S43	12	@ad<="20040401" and 'Nwell' and 'Pwell' and 'Nwell' and 'deep well'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 14:05
S44	16	@ad<="20040401" and 'first well' and 'second well' and 'third well' and 'deep well' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 14:14
S45	5	@ad<="20040401" and 'first well' and 'second well' with 'insulating' and 'third well' and 'latch up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 14:15
S46	1	@ad<="20040401" and 'first well' and 'second well' same 'sub well' and 'third well' and 'BJT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:01
S47	1	@ad<="20040401" and 'first well' and 'second well' and 'sub well' and 'third well' and 'BJT'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:01

S48	2	@ad<="20040401" and 'first well' and 'second well' and 'sub well' and 'third well'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:31
S49	330	@ad<="20040401" and 'NPN bipolar transistor' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:32
S50	132	@ad<="20040401" and 'NPN bipolar transistor' and 'pad' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:39
S51	330	@ad<="20040401" and 'CMOS' and 'bipolar transistor' and 'pad' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:39
S52	138	@ad<="20040401" and 'CMOS' and 'ESD' and 'bipolar transistor' and 'pad' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:47
S53	149	@ad<="20040401" and 'CMOS' and 'ESD' and 'bipolar transistor' and 'pad' and 'latch up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:59
S54	20	@ad<="20040401" and 'CMOS' and 'ESD' and 'bipolar transistor' and 'pad' and 'latch up' and 'well' with ('isolation' or 'insulating') with 'region'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/14 15:59
S55	9	'samsung' and 'BJT' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:19
S56	805	@ad<="20040401" and 'NPN' with 'bipolar junction transistor'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:22
S57	577	@ad<="20040401" and 'NPN' with 'bipolar junction transistor' and 'wells'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:22
S58	3	@ad<="20040401" and 'NPN' with 'bipolar junction transistor' and 'Nwell' and 'Pwell'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:28
S59	1	"20030137342".PN.	US-PGPUB	OR	ON	2005/06/15 08:24

S60	1	"20030117120".PN.	US-PGPUB	OR	ON	2005/06/15 08:24
S61	1	"6570437".PN.	USPAT; USOCR	OR	ON	2005/06/15 08:24
S62	40	@ad<="20040401" and 'NPN' with 'bipolar junction transistor' and 'isolation' with 'well'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:25
S63	3	@ad<="20040401" and 'NPN' same 'bipolar junction transistor' and 'Nwell' and 'Pwell'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:47
S64	1	"5489541".PN.	USPAT; USOCR	OR	ON	2005/06/15 08:35
S65	1	"5360750".PN.	USPAT; USOCR	OR	ON	2005/06/15 08:36
S66	1	"5163178".PN.	USPAT; USOCR	OR	ON	2005/06/15 08:37
S67	1	"5066602".PN.	USPAT; USOCR	OR	ON	2005/06/15 08:37
S68	1	"4966858".PN.	USPAT; USOCR	OR	ON	2005/06/15 08:39
S69	0	@ad<="20040401" and 'NPN' same 'lateral bipolar junction' and 'Nwell' and 'Pwell'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:48
S70	0	@ad<="20040401" and 'lateral bipolar junction' and 'Nwell' and 'Pwell'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:48
S71	97	@ad<="20040401" and 'lateral bipolar junction'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 08:51
S72	45	@ad<="20040401" and 'lateral' with 'bipolar junction' and 'ESD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 11:46
S73	1	"5637900".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:00
S74	1	"5473169".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:01
S75	1	"5637900".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:44
S76	1	"5473169".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:45
S77	1	"5455436".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:46

S78	1	"5432368".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:48
S79	1	"5430595".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:49
S80	1	"5330922".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:53
S81	1	"5132235".PN.	USPAT; USOCR	OR	ON	2005/06/15 09:53
S82	132	@ad<="20040401" and ('npn' or 'pnp') same 'bipolar junction' and 'ESD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 08:43
S83	14	@ad<="20040401" and 'vertical' with 'bipolar junction' and 'ESD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/15 11:46
S84	46	'Ker Ming-Dou' and 'latch up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 07:53
S85	1	"6043539".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:09
S86	1	"6011681".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:09
S87	1	"6002568".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:11
S88	1	"5959820".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:12
S89	1	"5945713".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:13
S90	1	"5917336".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:14
S91	1	"5400202".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:21
S92	1	"5359211".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:22
S93	1	"5289334".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:22
S94	1	"20020163009".PN.	US-PGPUB	OR	ON	2005/10/11 08:41
S95	1	"20020153570".PN.	US-PGPUB	OR	ON	2005/10/11 08:41
S96	138	@ad<="20040401" and ('npn' or 'pnp') same 'bipolar junction' and 'ESD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 09:25
S97	1	"20030214773".PN.	US-PGPUB	OR	ON	2005/10/11 08:43
S98	1	"20030147190".PN.	US-PGPUB	OR	ON	2005/10/11 08:44
S99	1	"6552886".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:48

S100	1	"6400540".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:48
S101	1	"6246079".PN.	USPAT; USOCR	OR	ON	2005/10/11 08:54
S102	1	"5786617".PN.	USPAT; USOCR	OR	ON	2005/10/11 09:00
S103	68	@ad<="20040401" and 'bipolar junction transistor' and 'pad' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 09:33
S104	206	@ad<="20040401" and 'bipolar junction transistor' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 09:26
S105	62	@ad<="20040401" and 'bipolar junction transistor' and 'n well' and 'p well' and 'latch-up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 09:34
S106	67	@ad<="20040401" and 'bipolar junction transistor' and 'n well' and 'p well' and 'latch up'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 09:50
S107	15	@ad<="20040401" and 'bjt' and 'first well' and 'second well' and 'third well'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/11 09:50